

PIMP31PA

50 V, 500 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 1 k Ω , R2 = 10 k Ω

31 August 2023

Product data sheet

1. General description

PNP/PNP Resistor-Equipped double Transistor (RET) in a medium power SOT1118 (DFN2020-6) leadless Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PIMN31PA

NPN/PNP complement: PIMC31PA

2. Features and benefits

- 500 mA output current capability
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

3. Applications

- Digital applications
- Cost-saving alternative to BC807 series in digital applications
- Control of IC inputs
- Switching loads

4. Quick reference data

| Table 1. Quick reference data | | | | | | | |
|-------------------------------|------------------------------|--------------------------|-----|-----|-----|------|------|
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
| Per transistor | | | | | | | |
| V _{CEO} | collector-emitter voltage | open base | | - | - | -50 | V |
| lo | output current | | | - | - | -500 | mA |
| R1 | bias resistor 1 (input) | T _{amb} = 25 °C | [1] | 0.7 | 1 | 1.3 | kΩ |
| R2/R1 | bias resistor ratio | | [1] | 9 | 10 | 11 | |

[1] See section "Test information" for resistor calculation and test conditions.

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5. Pinning information

| Table 2 | . Pinning info | rmation | | |
|---------|----------------|------------------------|----------------------|--------------------------|
| Pin | Symbol | Description | Simplified outline | Graphic symbol |
| 1 | GND1 | GND (emitter) TR1 | | O1 I2 GND2 |
| 2 | 11 | input (base) TR1 | 6 5 4 | |
| 3 | O2 | output (collector) TR2 | | |
| 4 | GND2 | GND (emitter) TR2 | 7 8 | |
| 5 | 12 | input (base) TR2 | | |
| 6 | 01 | output (collector) TR1 | 1 2 3 | |
| 7 | 01 | output (collector) TR1 | Transparent top view | |
| 8 | O2 | output (collector) TR2 | DFN2020-6 (SOT1118) | GND1 I1 O2 aaa-019790 |

6. Ordering information

Table 3. Ordering information

| Type number | Package | | | | |
|-------------|---------|---|----------------|--|--|
| | Name | Description | Version | | |
| PIMP31PA | | plastic, leadless thermal enhanced ultra thin small outline package; no leads; 6 terminals; 0.65 mm pitch; 2 mm x 2 mm x 0.65 mm body | <u>SOT1118</u> | | |

7. Marking

| Table 4. | Marking | codes |
|----------|---------|-------|
|----------|---------|-------|

| Type number | Marking code |
|-------------|--------------|
| PIMP31PA | 8G |

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

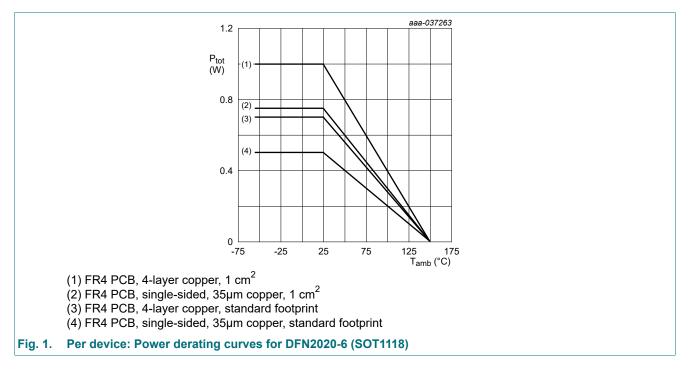
| Symbol | Parameter | Conditions | | Min | Мах | Unit |
|------------------|---------------------------|--------------------------|-----|-----|------|------|
| Per transiste | or | | I | | | |
| V _{CBO} | collector-base voltage | open emitter | | - | -50 | V |
| V _{CEO} | collector-emitter voltage | open base | | - | -50 | V |
| V _{EBO} | emitter-base voltage | open collector | | - | -5 | V |
| VI | input voltage | | | -10 | 5 | V |
| I _O | output current | | | - | -500 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 360 | mW |
| | | | [2] | - | 550 | mW |
| | | | [3] | - | 510 | mW |
| | | | [4] | - | 730 | mW |
| Per device | | | , | | | |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | [1] | - | 500 | mW |
| | | | [2] | - | 750 | mW |
| | | | [3] | - | 700 | mW |
| | | | [4] | - | 1 | W |
| Tj | junction temperature | | | - | 150 | °C |
| T _{amb} | ambient temperature | | | -55 | 150 | °C |
| T _{stg} | storage temperature | | | -65 | 150 | °C |

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided, 35µm copper, tin-plated; mounting pad for collector 1 cm².

[3] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

[4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated, mounting pad for collector 1 cm².



9. Thermal characteristics

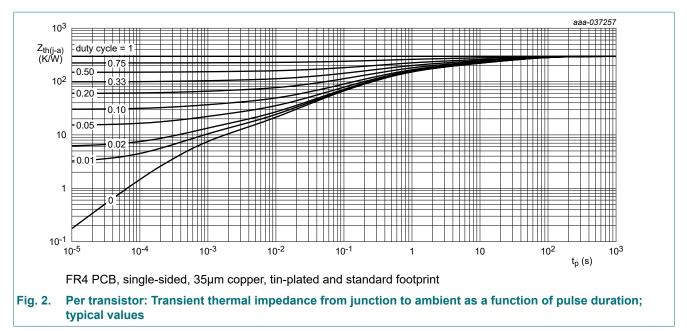
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|----------------------|-------------------------|---------------|-----|-----|-----|-----|------|
| Per transist | tor | | | | | | |
| R _{th(j-a)} | thermal resistance from | n in free air | [1] | - | - | 348 | K/W |
| junctio | junction to ambient | | [2] | - | - | 228 | K/W |
| | | | [3] | - | - | 246 | K/W |
| | | | [4] | - | - | 172 | K/W |
| Per device | | | | | | | |
| R _{th(j-a)} | thermal resistance from | in free air | [1] | - | - | 250 | K/W |
| | junction to ambient | | [2] | - | - | 167 | K/W |
| | | | [3] | - | - | 179 | K/W |
| | | | [4] | - | - | 125 | K/W |

[1] Device mounted on an FR4 PCB, single-sided, 35 μm copper, tin-plated and standard footprint.

[2] [3] Device mounted on an FR4 PCB, single-sided, 35µm copper, tin-plated; mounting pad for collector 1 cm².

Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.

Device mounted on an FR4 PCB, 4-layer copper, tin-plated; mounting pad for collector 1 cm². [4]



PIMP31PA

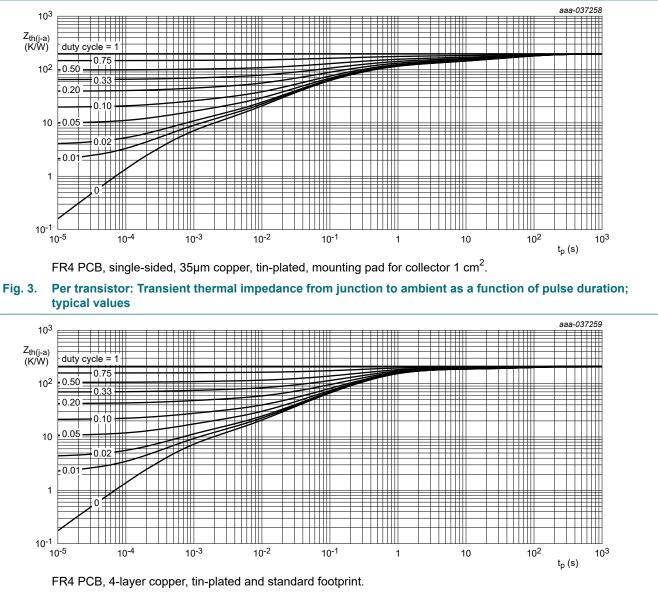
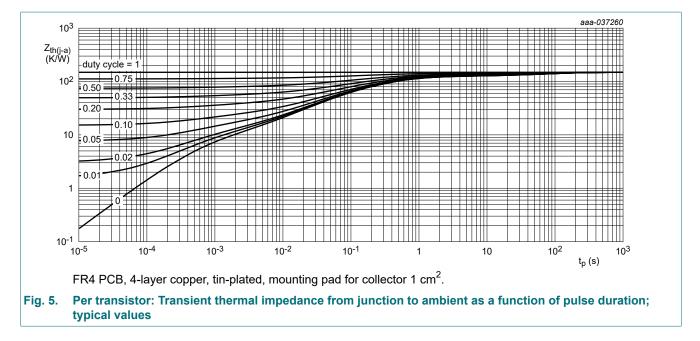


Fig. 4. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

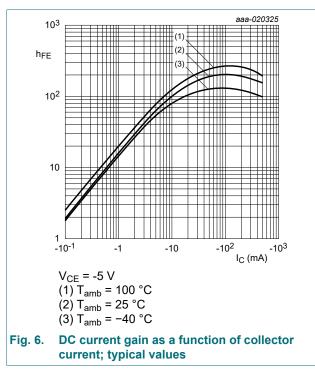


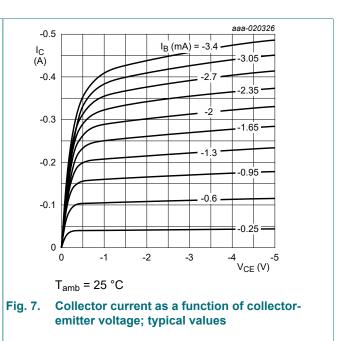
10. Characteristics

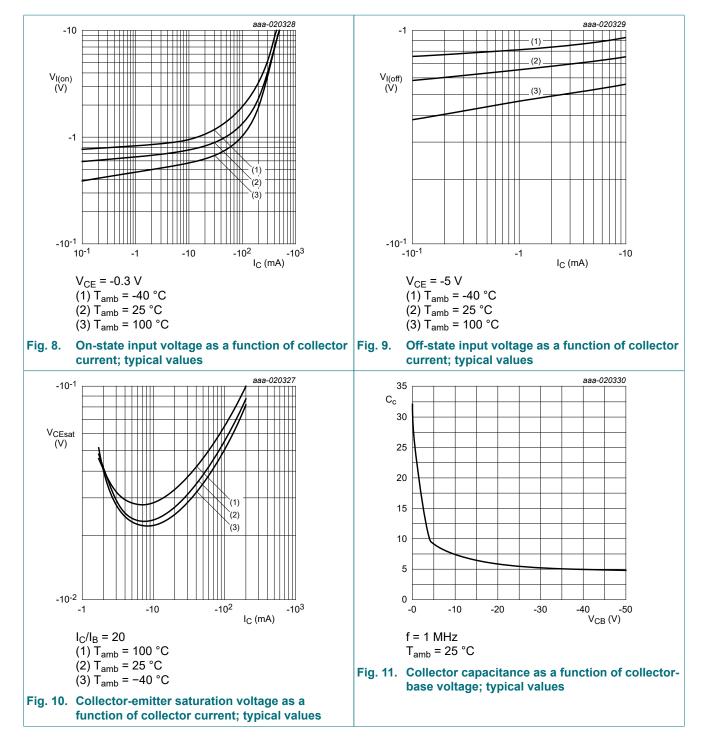
| Parameter | Conditions | | Min | Тур | Max | Unit |
|--|---|--|---|---|---|---|
| or | I | | | | | |
| collector-base breakdown voltage | I _C = -100 μA; I _E = 0 A; T _{amb} = 25 °C | | -50 | - | - | V |
| collector-emitter breakdown voltage | I _C = -10 mA; I _B = 0 A; T _{amb} = 25 °C | | -50 | - | - | V |
| collector-base cut-off current | V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C | | - | - | -100 | nA |
| collector-emitter cut-off current | V _{CE} = -50 V; I _B = 0 A; T _{amb} = 25 °C | | - | - | -0.5 | μA |
| emitter-base cut-off current | V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C | | - | - | -0.72 | mA |
| DC current gain | V_{CE} = -5 V; I _C = -50 mA; T _{amb} = 25 °C | | 70 | - | - | |
| collector-emitter saturation voltage | I_{C} = -50 mA; I_{B} = -2.5 mA; T_{amb} = 25 °C | | - | - | -100 | mV |
| off-state input voltage | V_{CE} = -5 V; I _C = -100 µA; T _{amb} = 25 °C | | -0.3 | -0.6 | -1 | V |
| on-state input voltage | V_{CE} = -0.3 V; I _C = -20 mA; T _{amb} = 25 °C | | -0.4 | -0.8 | -1.4 | V |
| bias resistor 1 (input) | T _{amb} = 25 °C | [1] | 0.7 | 1 | 1.3 | kΩ |
| bias resistor ratio | | [1] | 9 | 10 | 11 | |
| collector capacitance | V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C | | - | 7 | - | pF |
| transition frequency | V _{CE} = -5 V; I _C = -50 mA; f = 100 MHz; T _{amb} = 25 °C | [2] | - | 150 | - | MHz |
| | collector-base breakdown voltagecollector-emitter breakdown voltagecollector-emitter breakdown voltagecollector-base cut-off currentcollector-emitter cut-off currentemitter-base cut-off currentDC current gaincollector-emitter saturation voltageoff-state input voltageon-state input voltagebias resistor 1 (input)bias resistor ratiocollector capacitance | collector-base breakdown voltage $I_C = -100 \ \mu\text{A}; I_E = 0 \ \text{A}; T_{amb} = 25 \ ^{\circ}\text{C}$ collector-emitter breakdown voltage $I_C = -10 \ ^{\circ}\text{M}; I_B = 0 \ ^{\circ}\text{A}; T_{amb} = 25 \ ^{\circ}\text{C}$ collector-base cut-off current $V_{CB} = -50 \ ^{\circ}\text{V}; I_E = 0 \ ^{\circ}\text{A}; T_{amb} = 25 \ ^{\circ}\text{C}$ collector-emitter cut-off current $V_{CE} = -50 \ ^{\circ}\text{V}; I_B = 0 \ ^{\circ}\text{A}; T_{amb} = 25 \ ^{\circ}\text{C}$ emitter-base cut-off current $V_{CE} = -50 \ ^{\circ}\text{V}; I_B = 0 \ ^{\circ}\text{A}; T_{amb} = 25 \ ^{\circ}\text{C}$ DC current gain $V_{CE} = -5 \ ^{\circ}\text{V}; I_C = -50 \ ^{\circ}\text{M}; T_{amb} = 25 \ ^{\circ}\text{C}$ collector-emitter saturation voltage $I_C = -50 \ ^{\circ}\text{M}; I_B = -2.5 \ ^{\circ}\text{M}; T_{amb} = 25 \ ^{\circ}\text{C}$ off-state input voltage $V_{CE} = -5 \ ^{\circ}\text{V}; I_C = -100 \ ^{\circ}\text{A}; T_{amb} = 25 \ ^{\circ}\text{C}$ on-state input voltage $V_{CE} = -0.3 \ ^{\circ}\text{V}; I_C = -20 \ ^{\circ}\text{M}; T_{amb} = 25 \ ^{\circ}\text{C}$ bias resistor 1 (input) $T_{amb} = 25 \ ^{\circ}\text{C}$ bias resistor ratio $V_{CB} = -10 \ ^{\circ}\text{V}; I_E = 0 \ ^{\circ}\text{A}; I_B = 0 \ ^{\circ}\text{A}; I_E = 0 \ ^{\circ}\text$ | collector-base breakdown voltage $I_C = -100 \ \mu$ A; $I_E = 0 \ A$; $T_{amb} = 25 \ ^{\circ}C$ collector-emitter breakdown voltage $I_C = -10 \ ^{\circ}A$; $I_B = 0 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ collector-base cut-off current $V_{CB} = -50 \ ^{\circ}V$; $I_E = 0 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ collector-emitter cut-off current $V_{CE} = -50 \ ^{\circ}V$; $I_B = 0 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ emitter-base cut-off current $V_{CE} = -50 \ ^{\circ}V$; $I_B = 0 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ DC current gain $V_{CE} = -5 \ ^{\circ}V$; $I_C = 0 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ collector-emitter saturation voltage $I_C = -50 \ ^{\circ}A$; $I_B = -2.5 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ off-state input voltage $V_{CE} = -5 \ ^{\circ}V$; $I_C = -100 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ on-state input voltage $V_{CE} = -0.3 \ ^{\circ}V$; $I_C = -20 \ ^{\circ}A$; $T_{amb} = 25 \ ^{\circ}C$ bias resistor 1 (input) $T_{amb} = 25 \ ^{\circ}C$ bias resistor ratio $V_{CB} = -10 \ ^{\circ}V$; $I_E = 0 \ ^{\circ}A$; $I_E = 1 \ ^{\circ}HZ$; $I_E = 0 \ ^{\circ}A$; $I_E = 0 \ ^{\circ}A$; $I_E = 1 \ ^{\circ}A$; $I_E = 0 \ ^{\circ}A$; $I_E = 0 \ ^{\circ}A$; $I_E = 10 \ ^{\circ}A$; $I_E = 0 \ ^{\circ}A$; $I_E = $ | collector-base breakdown voltageIc = -100 μ A; IE = 0 A; Tamb = 25 °C-50collector-emitter breakdown voltageIc = -10 mA; IB = 0 A; Tamb = 25 °C-50collector-emitter breakdown voltageIc = -10 mA; IB = 0 A; Tamb = 25 °C-50collector-base cut-off currentVCB = -50 V; IE = 0 A; Tamb = 25 °C-collector-emitter cut-off currentVCE = -50 V; IB = 0 A; Tamb = 25 °C-collector-emitter cut-off currentVCE = -50 V; IB = 0 A; Tamb = 25 °C-collector-emitter cut-off currentVCE = -5 V; IC = 0 A; Tamb = 25 °C-DC current gainVCE = -5 V; IC = -50 mA; Tamb = 25 °C70collector-emitter saturation voltageIc = -50 mA; IB = -2.5 mA; Tamb = 25 °C-off-state input voltageVCE = -5 V; IC = -100 μ A; Tamb = 25 °C-off-state input voltageVCE = -0.3 V; IC = -20 mA; Tamb = 25 °C-0.3on-state input voltageVCE = -0.3 V; IC = -20 mA; Tamb = 25 °C-0.4bias resistor 1 (input)Tamb = 25 °C-0.4bias resistor 1 (input)Tamb = 25 °C-0.4bias resistor ratioVCB = -10 V; IE = 0 A; IE = 0 A; IE = 0 A; f = 1 MHz; Tamb = 25 °C-transition frequencyVCE = -5 V; IC = -50 mA; f = 100 MHz;- | or Ic = -100 μ A; I _E = 0 A; T _{amb} = 25 °C -50 - collector-base breakdown voltage Ic = -10 mA; I _B = 0 A; T _{amb} = 25 °C -50 - collector-emitter breakdown voltage Ic = -10 mA; I _B = 0 A; T _{amb} = 25 °C - - collector-base cut-off current V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C - - collector-emitter cut-off current V _{CE} = -50 V; I _B = 0 A; T _{amb} = 25 °C - - collector-emitter cut-off current V _{CE} = -50 V; I _C = 0 A; T _{amb} = 25 °C - - emitter-base cut-off current V _{EB} = -5 V; I _C = -50 mA; T _{amb} = 25 °C - - DC current gain V _{CE} = -5 V; I _C = -100 µA; T _{amb} = 25 °C - - collector-emitter saturation voltage Ic = -50 mA; I _B = -2.5 mA; T _{amb} = 25 °C - - off-state input voltage V _{CE} = -0.3 V; I _C = -20 mA; T _{amb} = 25 °C - - - bias resistor 1 (input) T _{amb} = 25 °C 10.7 1 1 9 10 collector capacitance V _{CB} = -10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C - 7 7 7 | or Ic = -100 μ A; I _E = 0 A; T _{amb} = 25 °C -50 - collector-base breakdown voltage Ic = -10 mA; I _B = 0 A; T _{amb} = 25 °C -50 - - collector-emitter breakdown voltage Ic = -10 mA; I _B = 0 A; T _{amb} = 25 °C -50 - - collector-base cut-off current V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C - - - collector-emitter cut-off current V _{CE} = -50 V; I _B = 0 A; T _{amb} = 25 °C - - - collector-emitter cut-off current V _{CE} = -50 V; I _B = 0 A; T _{amb} = 25 °C - - -0.5 emitter-base cut-off current V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C - - -0.72 DC current gain V _{CE} = -5 V; I _C = -50 mA; T _{amb} = 25 °C - - - -0.72 DC current gain V _{CE} = -5 V; I _C = -100 µA; T _{amb} = 25 °C - - - -100 off-state input voltage V _{CE} = -5 V; I _C = -20 mA; T _{amb} = 25 °C -0.3 -0.6 -1 on-state input voltage V _{CE} = -0.3 V; I _C = -20 mA; T _{amb} = 25 °C -0.4 -0.8 -1.4 bias resistor ratio V _{CB} = -10 V; I _E = 0 A; I _e = 0 A; - 7 |

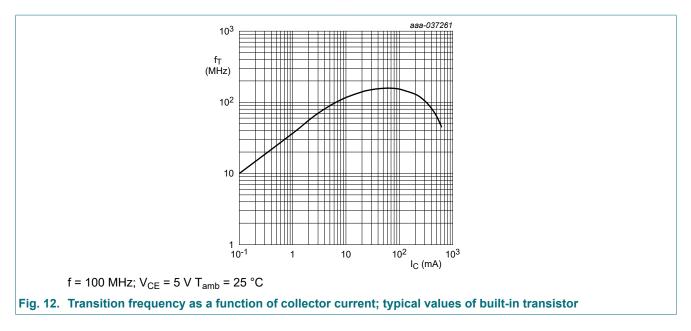
[1] See section "Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor.









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11. Test information

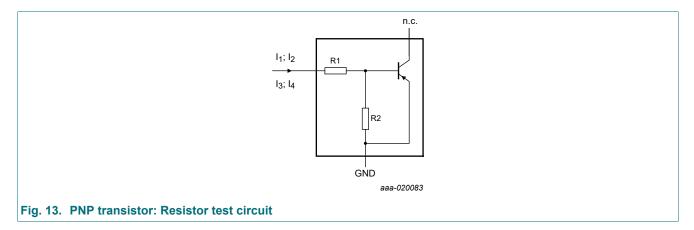
Resistor calculation

Calculation of bias resistor 1 (R1):

$$R_1 = \frac{V(I_2) - V(I_1)}{I_2 - I_1}$$

Calculation of bias resistor ratio (R2/R1):

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$

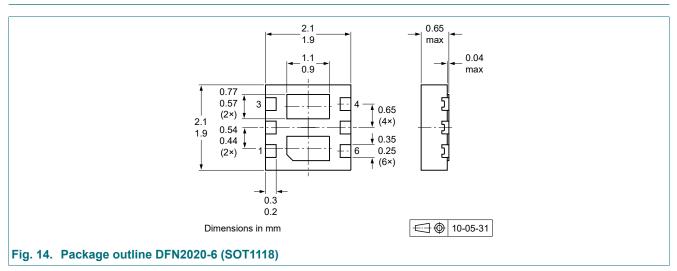


Resistor test conditions

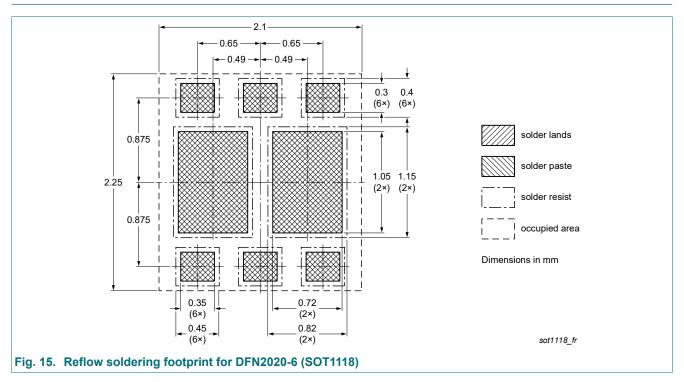
Table 8. Resistor test conditions

| PIMP31PA | R1 (kΩ) | R2 (kΩ) | Test conditions | | | |
|---------------|---------|---------|-----------------|----------------|----------------|----------------|
| | | | I ₁ | l ₂ | l ₃ | I ₄ |
| TR1/TR2 (PNP) | 1 | 10 | -0.7 mA | -0.8 mA | 0.45 mA | 0.55 mA |

12. Package outline



13. Soldering



Product data sheet

14. Revision history

| Table 9. Revision history | | | | | |
|---------------------------|--------------|--------------------|---------------|------------|--|
| Data sheet ID | Release date | Data sheet status | Change notice | Supersedes | |
| PIMP31PA v.1 | 20230831 | Product data sheet | - | - | |

PIMP31PA

15. Legal information

Data sheet status

| Document status [1][2] | Product status [3] | Definition |
|-----------------------------------|-----------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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